

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MET240AFK, TC7MET244AFK

Octal Bus Buffer

TC7MET240AFK Inverted, 3-State Outputs

TC7MET244AFK Non-Inverted, 3-State Outputs

The TC7MET240AFK and 244AFK are advanced high speed CMOS octal bus buffers fabricated with silicon gate C²MOS technology. They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The TC7MET240AFK is an inverting 3-state buffer having two active-low output enables. TC7MET244AFK is a non-inverting 3-state buffer, and has two active-low output enables.

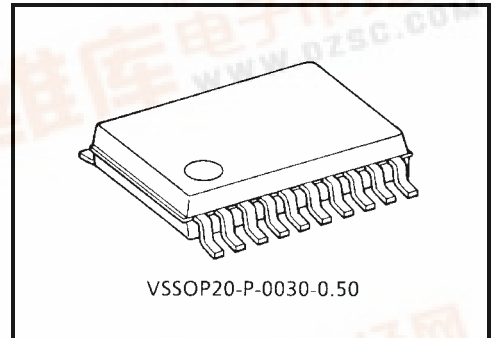
These devices are designed to be used with 3-state memory address drivers, etc.

The input voltage are compatible with TTL output voltage.

These devices may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (*) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

*: output in off-state

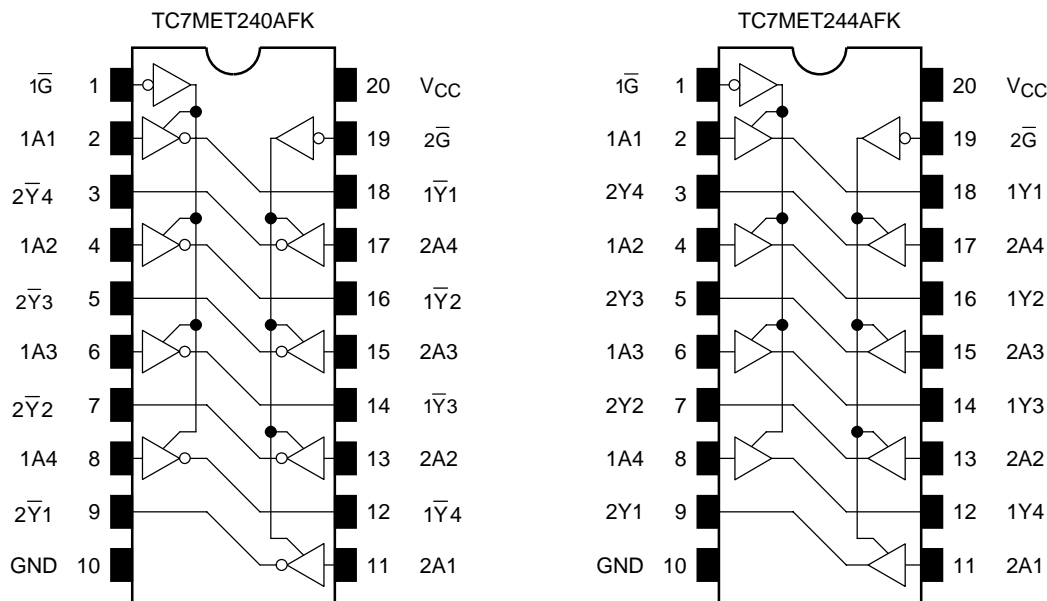


Weight: 0.03 g (typ.)

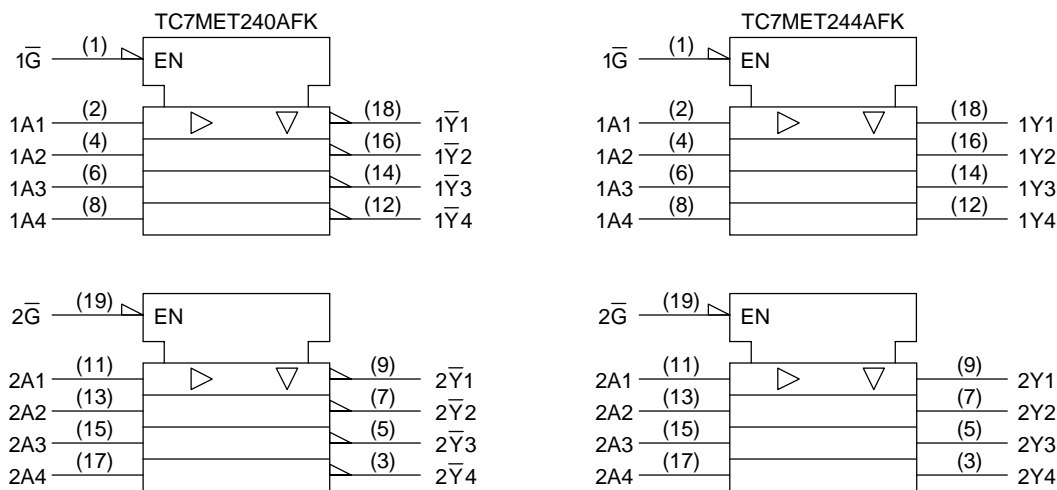
Features

- High speed: $t_{pd} = 5.6 \text{ ns}$ (typ.) ($V_{CC} = 5 \text{ V}$)
- Low power dissipation: $I_{CC} = 4 \mu\text{A}$ (max) ($T_a = 25^\circ\text{C}$)
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V}$ (max)
 $V_{IH} = 2.0 \text{ V}$ (min)
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Low noise: $V_{OLP} = 1.0 \text{ V}$ (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 240/244 type.

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs		Outputs	
\bar{G}	A_n	Y_n	\bar{Y}_n
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

Y_n : TC7MET244AFK

\bar{Y}_n : TC7MET240AFK

Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5~7.0	V
DC input voltage	V_{IN}	-0.5~7.0	V
DC output voltage	V_{OUT}	-0.5~7.0 (Note1)	V
		-0.5~ $V_{CC} + 0.5$ (Note2)	
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	±20 (Note3)	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC} /ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65~150	°C

Note1: Output in off-state

Note2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~5.5 (Note4)	V
		0~ V_{CC} (Note5)	
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~20	ns/V

Note4: Output in off-state

Note5: High or low state

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
					VCC (V)	Min	Typ.	Max	Min		Max
Input voltage	High level	VIH	—		4.5~5.5	2.0	—	—	2.0	—	V
	Low level	VIL	—		4.5~5.5	—	—	0.8	—	0.8	
Output voltage	High level	VOH	VIN = VIH or VIL	I _{OH} = -50 μA	4.5	4.4	4.5	—	4.4	—	V
				I _{OH} = -8 mA	4.5	3.94	—	—	3.80	—	
	Low level	VOL	VIN = VIH or VIL	I _{OL} = 50 μA	4.5	—	0	0.1	—	0.1	
				I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
3-state output off-state current		IOZ	VIN = VIH or VIL VOUT = VCC or GND		5.5	—	—	±0.25	—	±2.50	μA
Input leakage current		IN	VIN = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		ICC	VIN = VCC or GND		5.5	—	—	4.0	—	40.0	μA
		ICCT	Per input: VIN = 3.4 V Other input: VCC or GND		5.5	—	—	1.35	—	1.50	mA
Output leakage current		IOPD	VOUT = 5.5 V		0	—	—	0.5	—	5.0	μA

AC Characteristics (Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (TC7MET240AFK)	t _{pLH} t _{pHL}	—	5.0 ± 0.5	15	—	5.6	7.8	1.0	9.0	ns
				50	—	6.1	8.8	1.0	10.0	
Propagation delay time (TC7MET244AFK)	t _{pLH} t _{pHL}	—	5.0 ± 0.5	15	—	5.4	7.4	1.0	8.5	ns
				50	—	5.9	8.4	1.0	9.5	
3-state output enable time	t _{pZL} t _{pZH}	R _L = 1 kΩ	5.0 ± 0.5	15	—	7.7	10.4	1.0	12.0	ns
				50	—	8.2	11.4	1.0	13.0	
3-state output disable time	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	5.0 ± 0.5	50	—	8.8	11.4	1.0	13.0	ns
Output to output skew	t _{osLH} t _{osHL}	(Note6)	5.0 ± 0.5	50	—	—	1.0	—	1.0	ns
Input capacitance	C _{IN}	—			—	4	10	—	10	pF
Output capacitance	C _{OUT}	—			—	9	—	—	—	pF
Power dissipation capacitance (Note7)	C _{PD}	TC7MET240AFK			—	19	—	—	—	pF
		TC7MET244AFK			—	18	—	—	—	

Note6: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

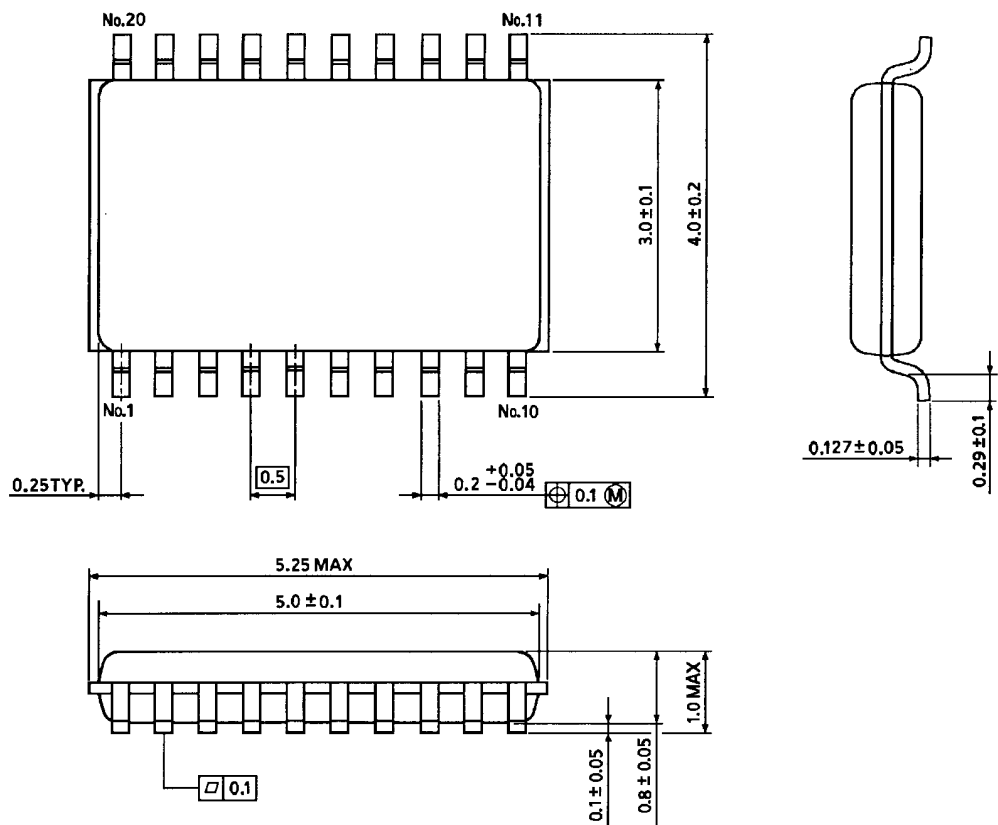
Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V _{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	V
Minimum high level dynamic input voltage V _{IH}	V _{IHD}	C _L = 50 pF	5.0	—	2.0	V
Maximum high level dynamic input voltage V _{IL}	V _{ILD}	C _L = 50 pF	5.0	—	0.8	V

Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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